



Novel Techniques for generation of ultraspectrally pure signals, and ultra-high dynamic range true time delay for optical signal processing

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Objective

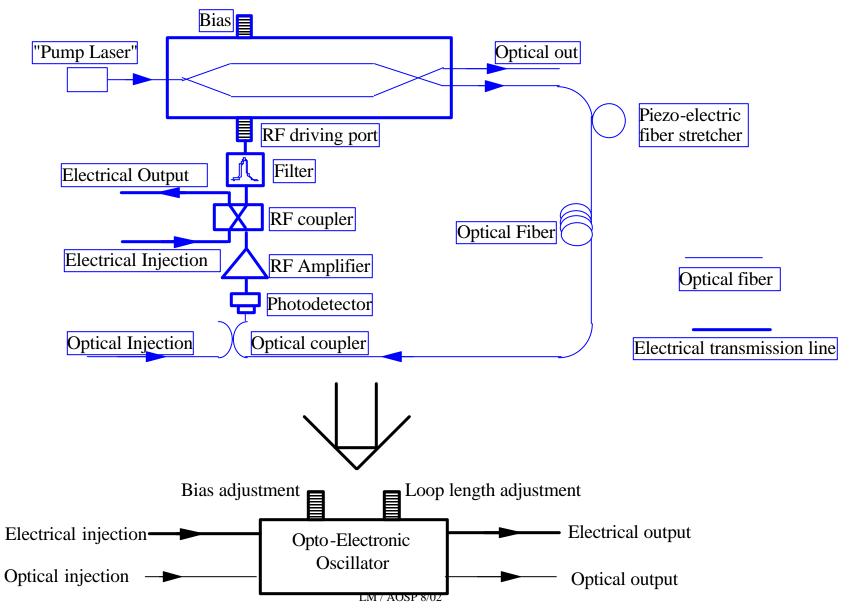


- Develop an improved performance Opto-Electronic Oscillator (25 dB phase noise improvement across the Fourier spectrum)
- Develop a novel widely tunable true time delay device based on quantum coherence control



OEO as a Generic Frequency Control Device





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OEO



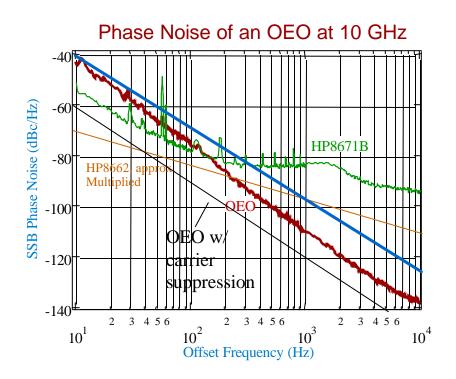
Some significant features

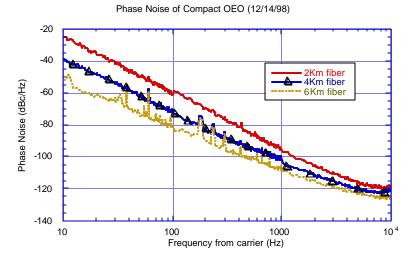
- OEO is a generic device: various configurations of lasers, modulators, optical delays can be implemented
- OEO lends itself to diverse architecture (dual loop, Coupled OEO, etc) to support diverse applications
- OEO's performance will improve with improved components (amplifiers, lasers, modulators, detectors, optical delays)
- OEO is ideal for opto-electronic integration
- The OEO signal is available both electrically, and on an optical carrier
- The COEO version generates short (sub-picosecond) mode locked optical pulses with lowest jitter
- OEO can be phase locked, frequency locked, self locked, and used as a VCO

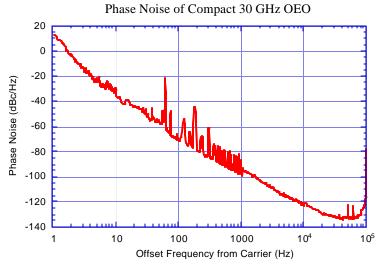




10 GHz OEO











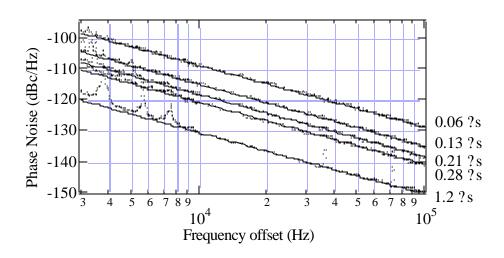
Demonstrated features of OEO

- Highest demonstrated spectral purity for any <u>open loop</u> oscillator at 10 GHz (-145 dBc/Hz at 10 kHz from the carrier)
- Demonstration of up to 20 dB better performance than this, at frequencies close to carrier, with carrier suppression technique
- Demonstrated 30 GHz oscillator, with spectral purity of -120 dBc/Hz at 10 kHz from the carrier, limited only by the amplifier
- Demonstrated that low noise OEO is also inherently insensitive to acceleration: 10 GHz OEO exhibits the lowest acceleration sensitivity of any oscillator, with room to improve.
- Demonstrated that the OEO fiber spool may be replaced by a sub-millimeter microsphere, and designed a chip based OEO
- Demonstrated wideband and narrowband tuning with a 10 GHz OEO
- Demonstrated multi-tone and enhanced filtering with dual-loop

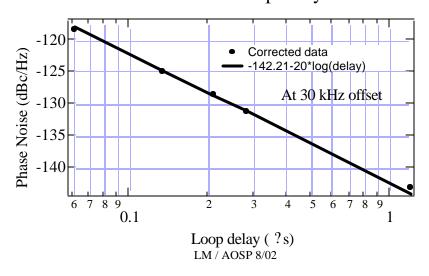




Phase noise vs. frequency offset



Phase noise vs. loop delay time

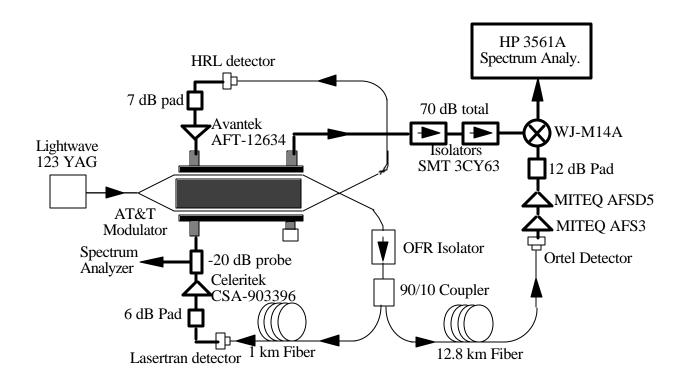


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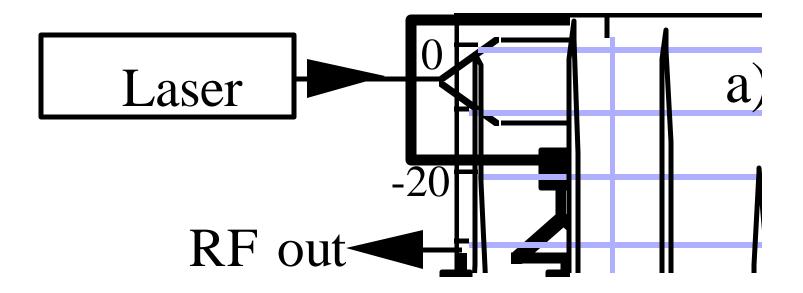
Noise Measurement Set Up







The Dual-Loop OEO



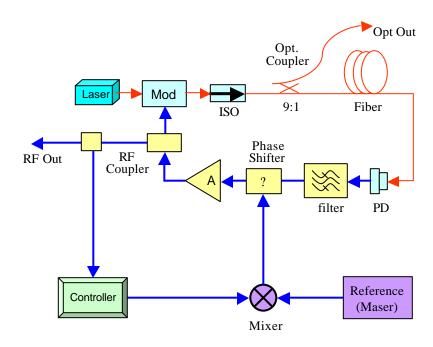
Reduces side modes to lower than -100 dBc



A Phase Locked Optoelectronic Oscillator



Phase Locked OEO / Optical Synthesizer

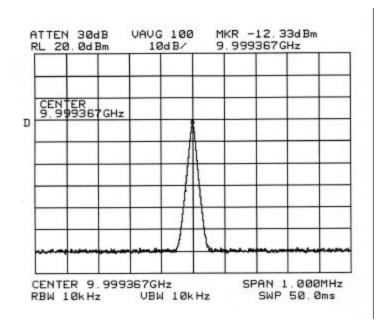


Phase locking of the OEO allows its use as a local oscillator to achieve long term stability. This capability is needed, for example, to enable *GPS style navigation at Mars*.

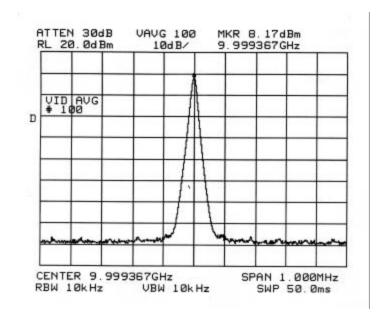




Signal to Noise ratio of the injected and injection Locked signals



(a) Injected signal from HP synthesizer



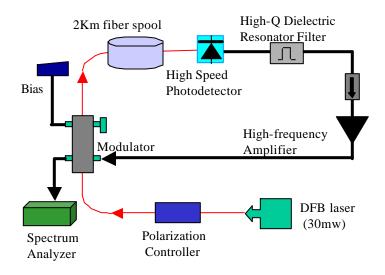
(b) Signal of injection locked OEO (nearest side modes at 90kHz suppressed by >15dB)



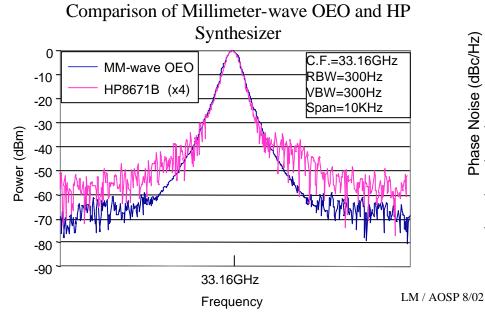
Ka-Band / Millimeter-wave OEO

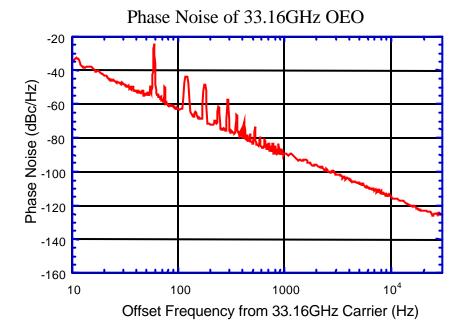


SHH7043/091901



- Oscillating up to 33 GHz.
- Phase noise less than -30dBc/Hz at 10Hz and -120dBc/Hz at 10 KHz from both 28.29GHz and 33.16GHz carriers.
- Phase noise of mm-wave OEO is 20dB lower than that of the HP synthesizer with a 4? multiplier.







Frequency Tunable OEO

10.413730E

10.413720

10.413710

10.413700

10.413690

10.413680

10.413670



11.234695

11.234685 11.234675

11.234675 11.234665

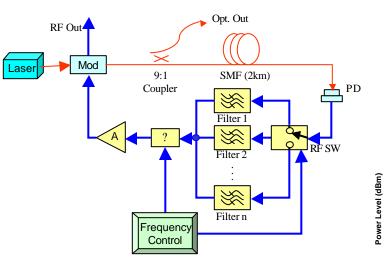
11.234655

11.234645 **3**

11.234635

Tunable OEO Frequency vs. Control Voltage (01/04/01)

Frequency tunability will enhance the use of the OEO as a VCO for communications and radar applications



Frequency Tunable OEO

11.234625 10.413660 11.234615 **ட** 10.413650 11.234605 10.413640 11.234595 10.413630E 10.413620 11.234585 5.0 10.0 15.0 20.0 25.0 30.0 0.0 Control Voltage (V) Spectrum of OEO5 (Tune frequency by changing control voltage) Pmin: -21.8dBm -10 -20 -30

-40

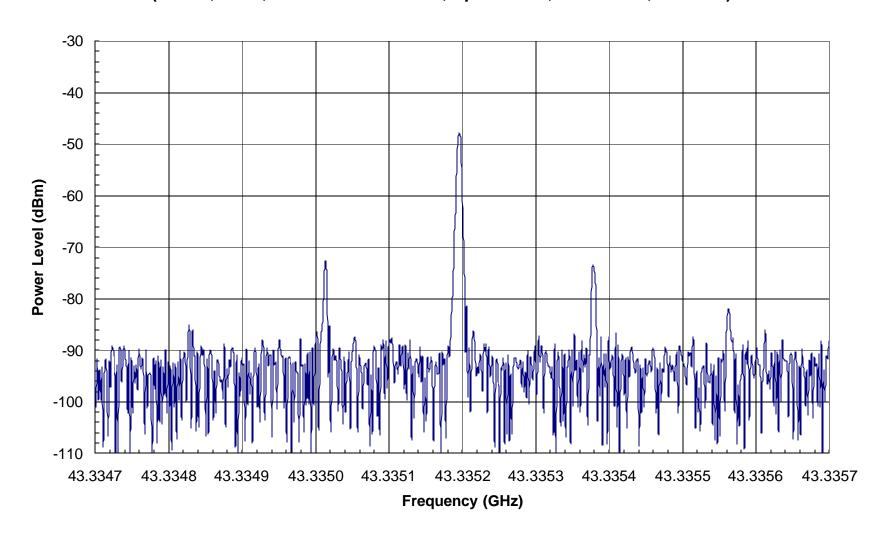
-80



Ka-Band / Millimeter-wave OEO



Spectrum of KaOEO03 (SP109, 100N, fc:43.335243450GHz, Span:1MHz, RBW:3kHz, 09/10/01)





Packaged OEO with Vibration Compensation





 Packaged OEO with vibration compensation (reduced the acceleration sensitivity).

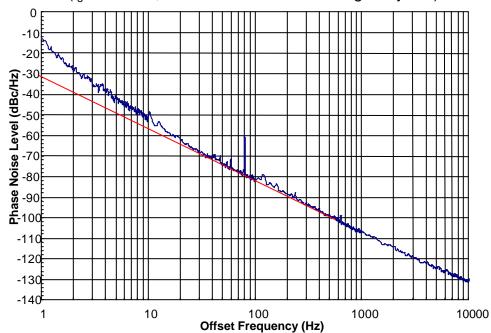
Vibration Test Results (without fiber delay line compensation) OEO-2, Fc=11.763 GHz, Fv=40 Hz, Value in 10⁻¹⁰/G

Number of Test	? x	? y	? z	??
1	0.713	0.650	32.259	32.273
2	0.465	0.900	32.146	32.162
3	0.453	1.124	30.870	30.894
4	0.584	0.982	31.484	31.505
5	0.556	0.485	33.886	33.894
Average	0.554	0.828	32.129	32.144

Vibration Test Results (with fiber delay line compensation)
OEO-2, Fc=11.763 GHz, Fy=40 Hz, Value in 10⁻¹⁰/G

OEO-2, FC=11.763 GHZ, FV=40 HZ, Value III 10 47G						
Number of Test	?x	? y	?z	??		
1	0.713	0.650	0.970	1.368		
2	0.465	0.900	1.140	1.525		
3	0.453	1.124	0.460	1.296		
4	0.584	0.982	0.820	1.406		
5	0.556	0.485	0.740	1.045		
Average	0.554	0.828	0.826	1.294		

Phase Noise (f_o=6.12GHz, with 4km fiber as the *testing* delay line)







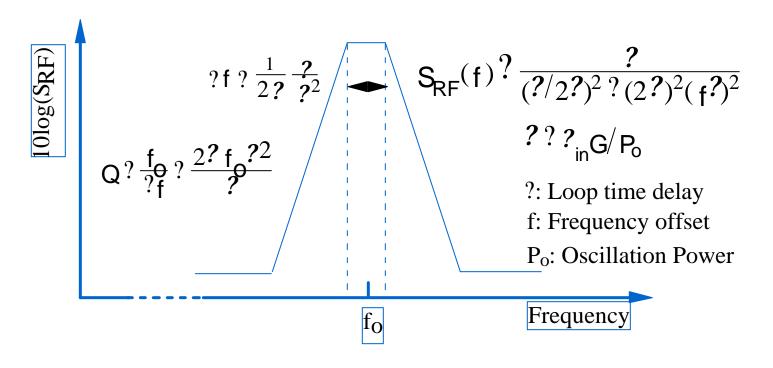
OEO Sources of Noise

Analysis of the OEO noise sources



Theory of OEO's Noise





?i ==> Input noise power density
?in ? Thermal noise ? Shot noise ? Laser RIN noise

- * Noise decays with f: 20 dB/Decade
- * Noise decays with ??20 dB/decade
- * Noise is independent of oscillation frequency f_O.
- * Q increases with f₀.

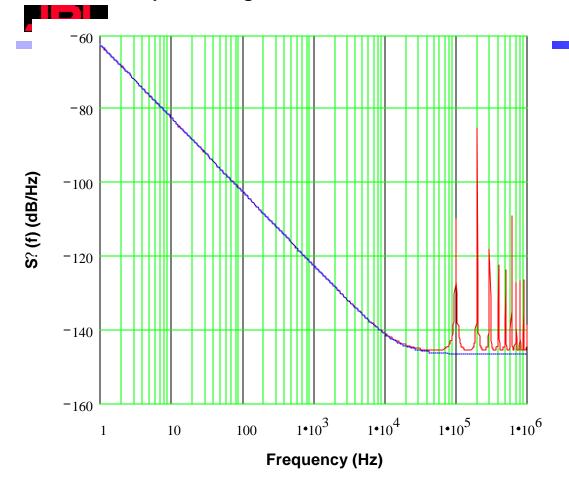
Typical ? ~ 5 x $10^{-17}/\text{Hz}$

For ? = 6 ? s (1 km fiber)

 $Q \sim 4 \times 10^{-5} f_0 (Hz)$

Graph showing resonances in 2km fiber





Mathcad plot of 2 forms of Sphi at bottom of this page (Srf and Srff). The first form is a low-frequency approximation plotted as the dashed line. Using white noise sources only here.

$$?N = kb Tnf(NF?T) + 2 eminus Iph R + Nrin Iph^2 R$$

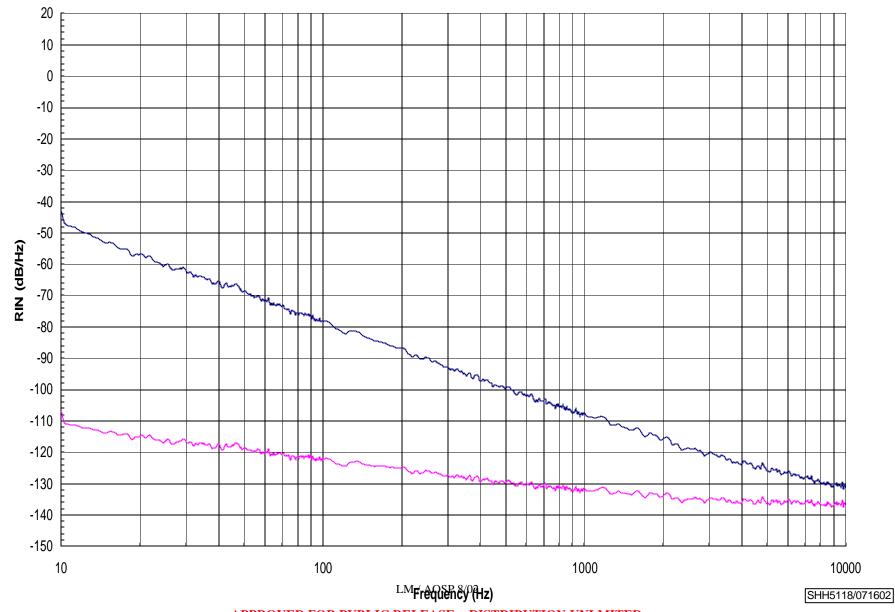
$$? = \frac{?N}{Posc}$$

Srf(f) = ?
$$\left[1 + \frac{1}{(2^{\frac{1}{2}, \frac{1}{2}, \frac{1}{2})^2}\right]$$
 Srff(g) = ? $\left[1 + \frac{1}{2}, \frac{1}{(1 - \cos(2^{\frac{1}{2}, \frac{1}{2}, \frac{1}{2}))}\right]$



RIN of Semiconductor Laser (LN010, Alcatel A1915LMI, I:60mA, P:4.8mW, Pr:3mW, 07/15/02)



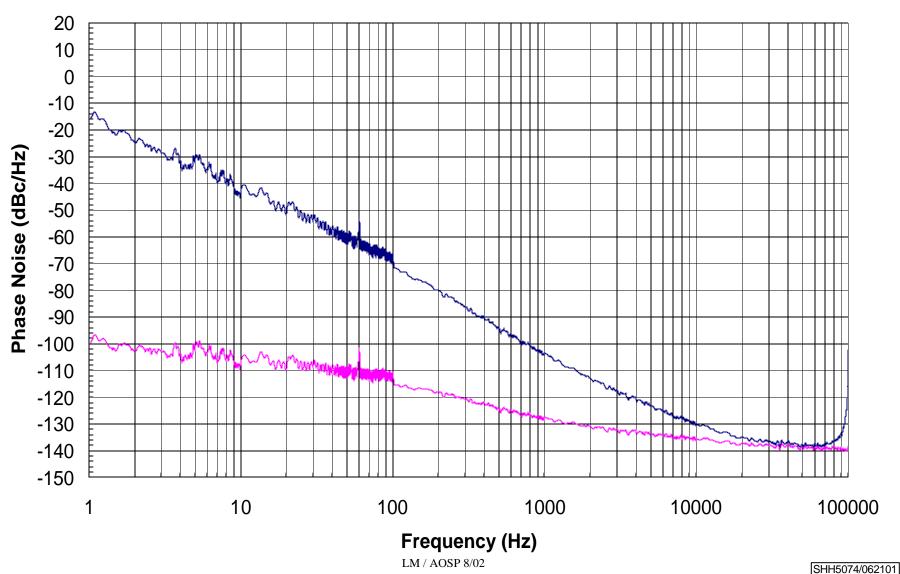






Phase Noise of Amplifier

(PNAMP50, MSH-6642501-LP, S/N:104, fc:10.58GHz, 11/17/00)

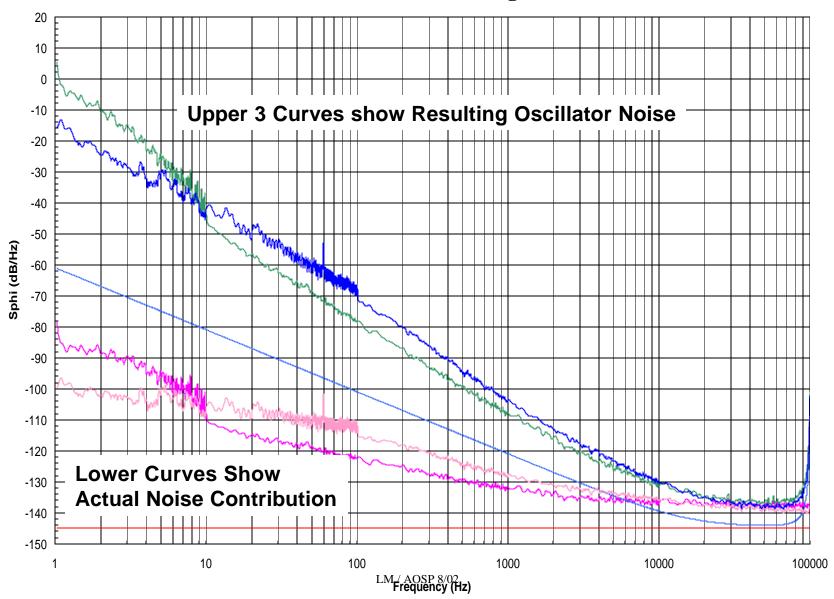




Shot Noise, RIN, and Amplifier Noise



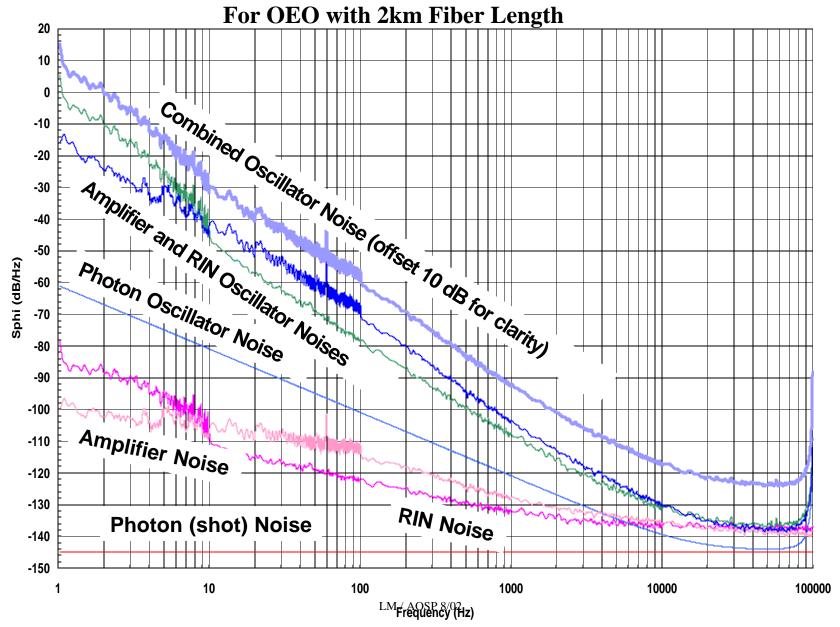
OEO with 2km Fiber Length





Noise Sources and Effect on Phase Noise

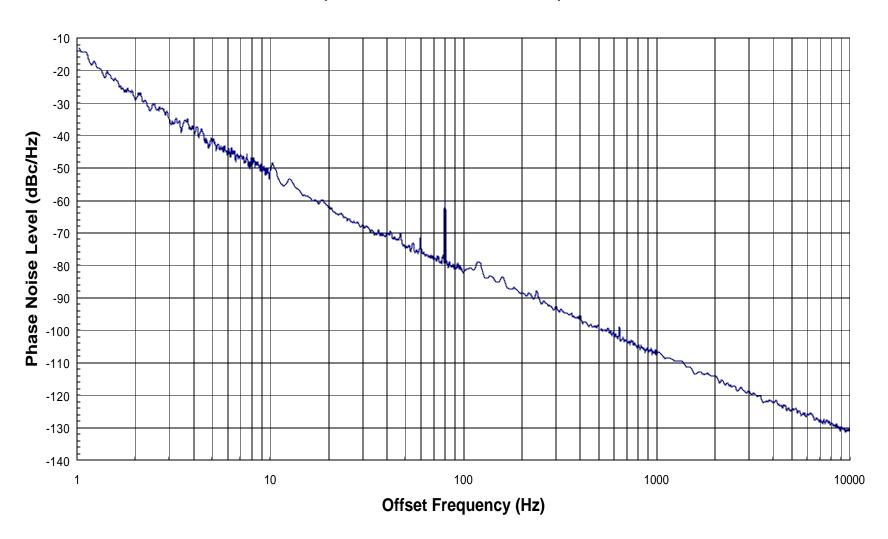








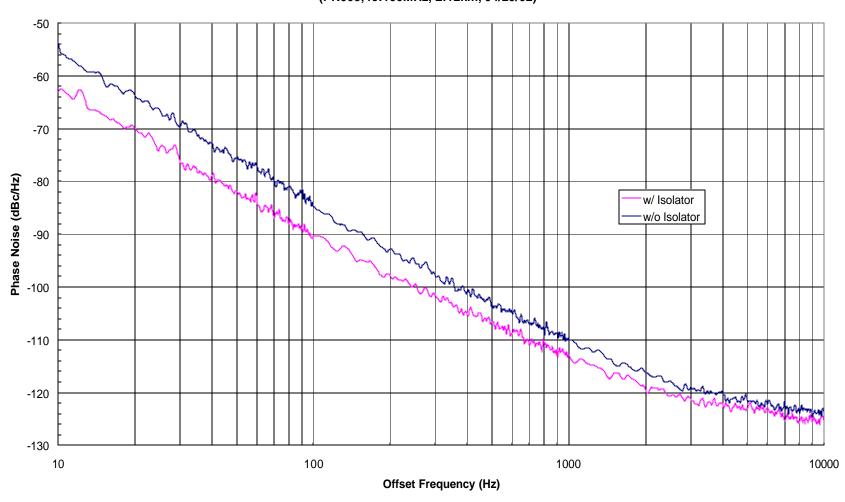
Phase Noise of OEO3 (PN-FR-06, fc:6.12GHz, 08/17/00)







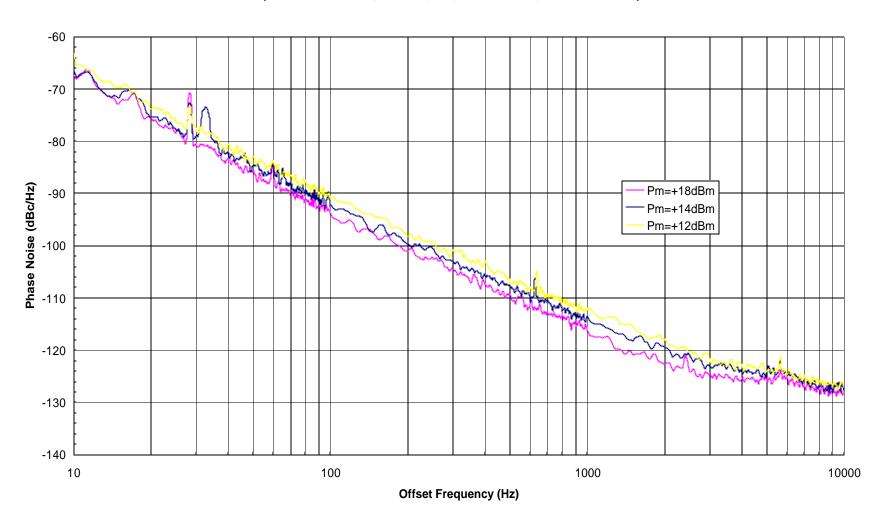
Open Loop Phase Noise vs. Optical Isolator (Measured by Maser) (PN005, fc:100MHz, L:12km, 04/29/02)







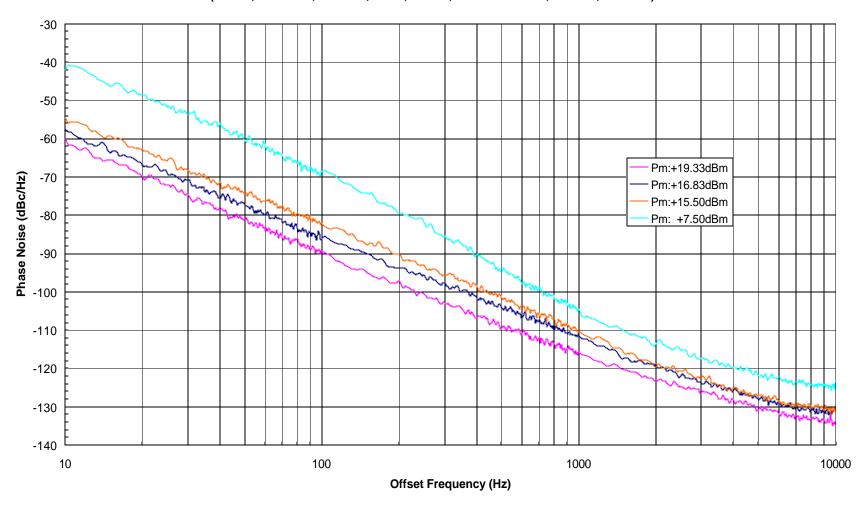
Open Loop Phase Noise vs. Modulation Power (Measured by Maser) (PN005, fc:100MHz, Pm:+18, +14, and +12dBm, L:4km, 05/16/02)







OEO with Directly Modulated Laser (PN001, fc:90MHz, Pm:+7.5, +15.5, +16.83, and +19.33dBm, Lo:4km, 06/19/02)



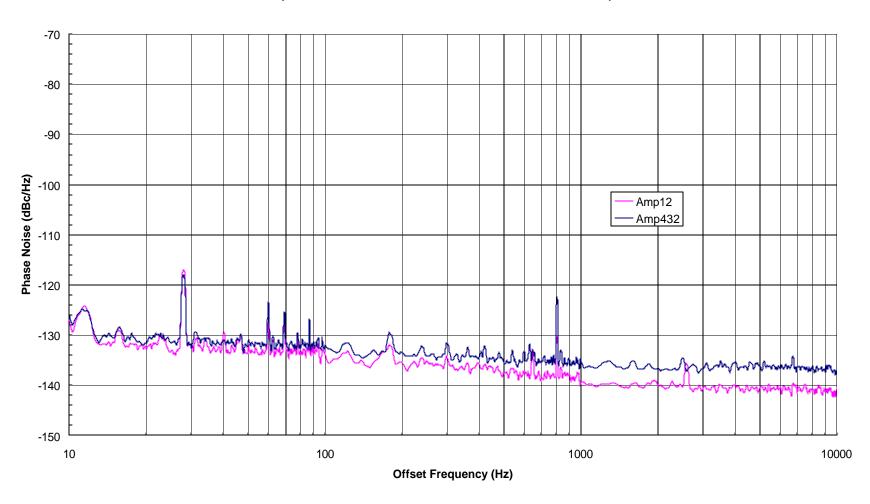
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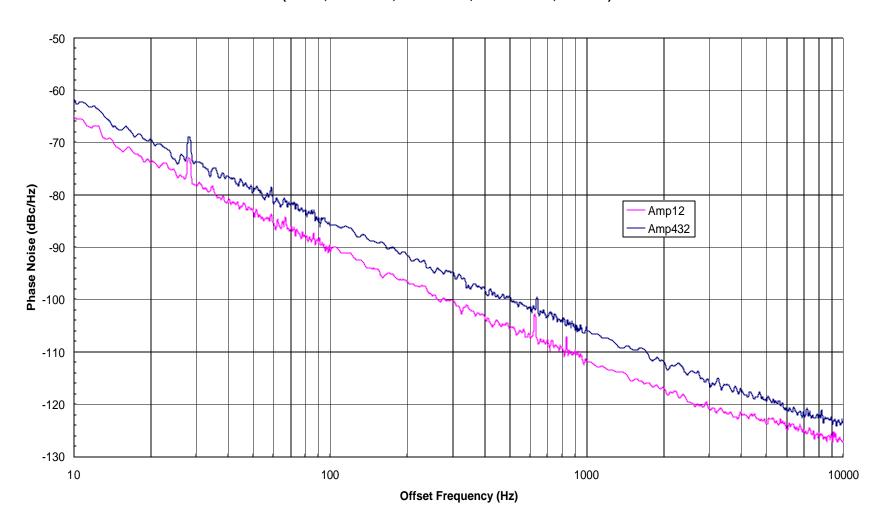
Amplifier Phase Noise vs. Noise Figure (PN002, fc:100MHz, NF12=2.4dB, NF432=7.5dB, 05/14/02)







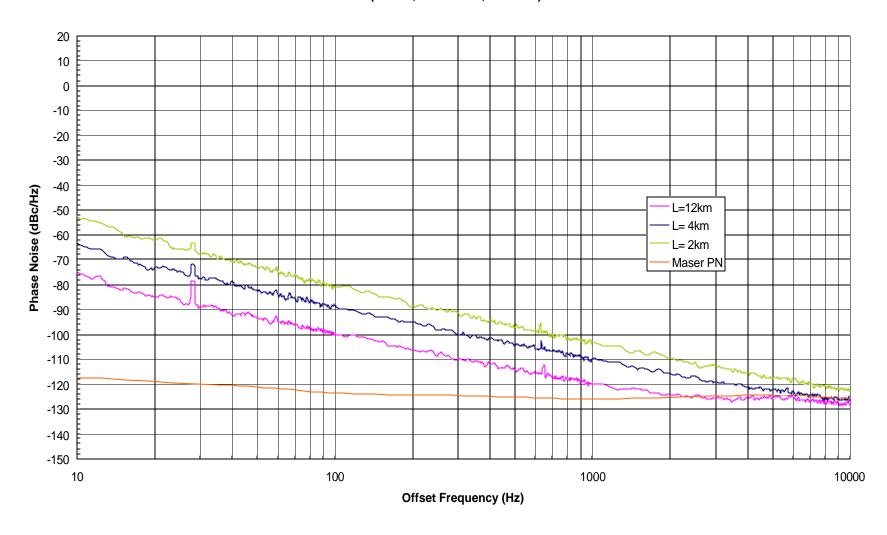
Open Loop Phase Noise vs. Amplifier Performance (PN007, fc:100MHz, NF12=2.4dB, NF432=7.5dB, 04/18/02)







Phase Noise Sensivity vs. Length of Fiber Delay Line (PN004, fc:100MHz, 04/18/02)





Strategies for improving performance

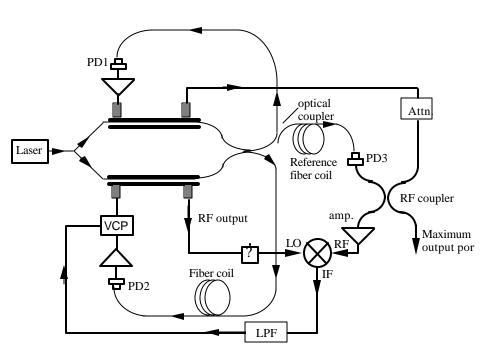


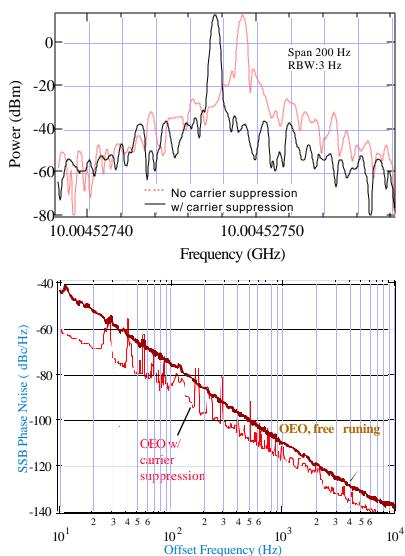
- Implement configuration without the us of an amplifier to reduce close to carrier noise
 - High efficiency modulator
- Implement carrier suppression technique
 - Cancels the amplifier noise
 - Cancels residual laser RIN nois
 - Eliminates all other common noise sources



OEO with Carrier Suppression



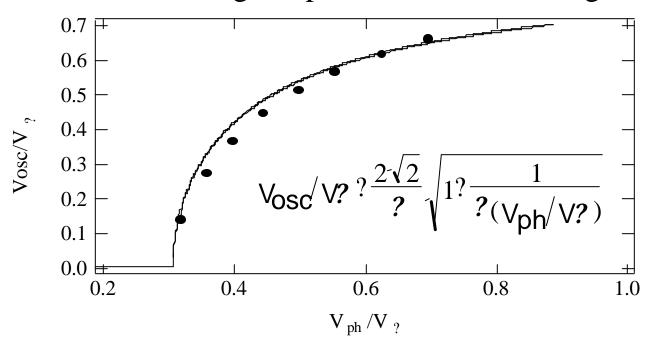








Oscillating Amplitude vs. Photovoltage



 $V_{ph} = I_{ph} *R *G \qquad \text{is the photovoltage across the E/O modulator} \\ I_{ph} : \text{Photocurrent.} \qquad \text{G: Amplifier voltage gain}$

R: Modulator input impedance

Threshold photovoltage: $V_{ph}?V_{?}/?$

For I_{ph} of 20 mA, R of 50 ? , V? < 3.14 volts ==>No amplifier is required for oscillation.





Microsphere -- a low-loss photon trap, efficient optical cavity

Whispering-gallery modes - closed circular waves under total internal reflection (Term by J.W.S.Rayleigh, analogy to acoustic modes in the gallery of St Paul cathedral)

(MUST BE) Sustained in any axisymmetric dielectric body with R???

low material loss (transparent material, e.g fiber grade silica)

low bending loss $(R \gg ?)$

low scattering loss (TIR always under grazing incidence

+ molecular-size surface roughness)

Quality-factor Q = ???? RES - up to $\sim 10^{10}$

Photon lifetime ???Q/2?c - up to $\sim 3?s$

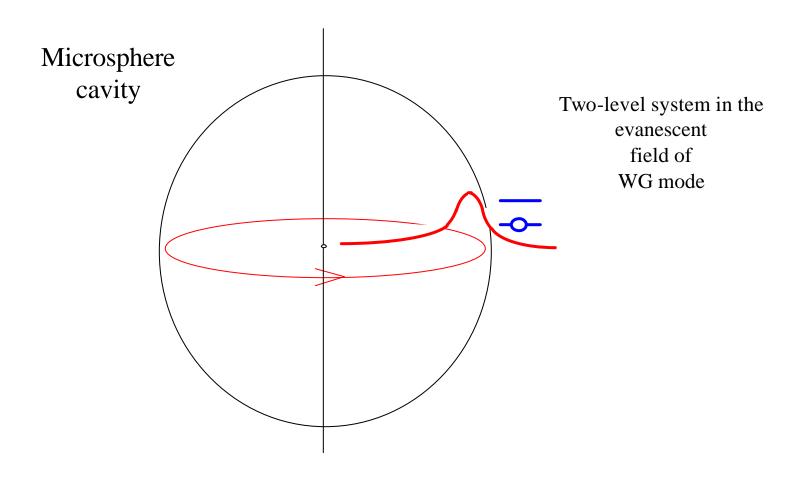
(cavity ringdown time)

visible and near-infrared band: Opt.Lett. 21, p.453 (1996)

Opt.Lett. 23, p.247 (1998)







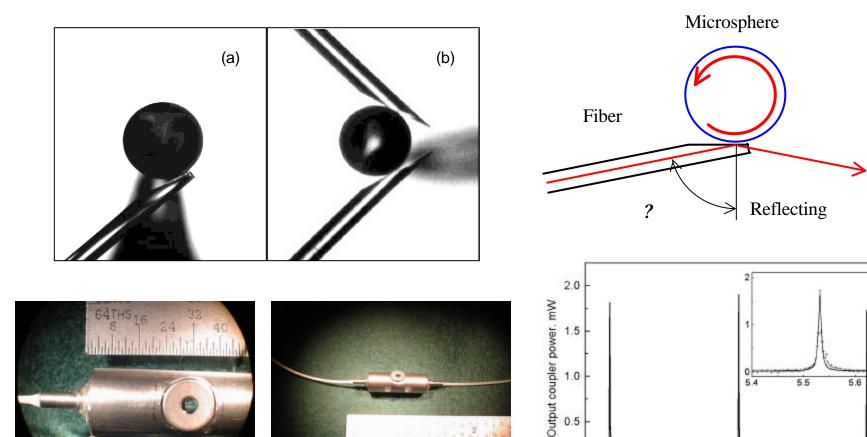
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Fiber-optic integration: a "pigtailing" method for microspheres



Laser frequency tuning, GHz



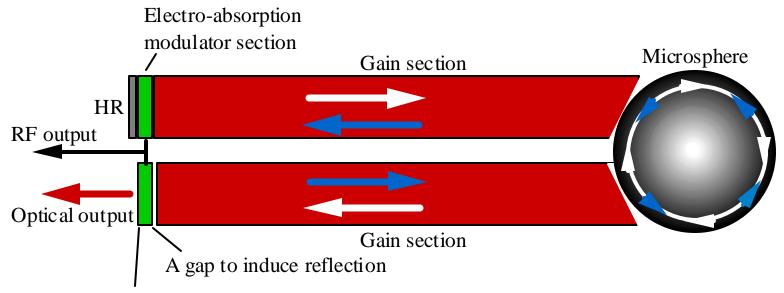
Maximum transmission at resonance ~23.5% (fiber-to-fiber loss 6.3dB); $Q_{load} > 3.210^7$ at 1550nm; sphere diameter 405? m. Unloaded Q_o ? $1.2.210^8$.

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Proposed mm-wave OEO-on-Chip



Photodetector (reversely biased electro-absorption modulator)



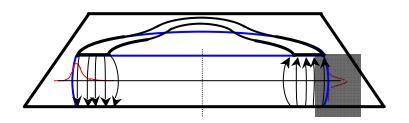


LiNbO₃Toroidal Whispering-Gallery Resonators for Ka Band Electro-Optical Modulation:

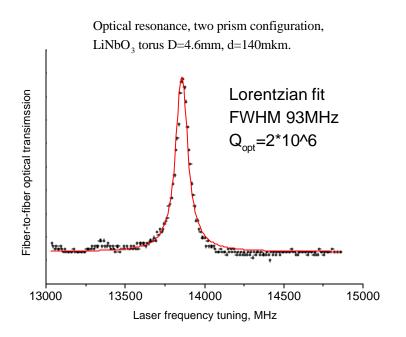


Diameter 1.45mm, Thickness 110micron, Transverse curvature radius 65micron, Optical Q ~ 10⁶, Optical FSR 33GHz





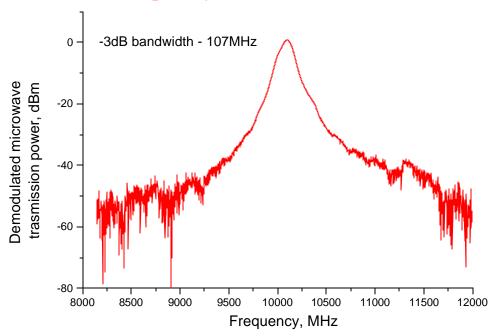
Optical resonance



Diameter D=4.6mm, transverse diameter d=140mkm, height h=110mkm, FSR=10.0 GHz at 1550nm, optical Q = (2...5)*10^6, DC electrical tunability 5GHz

<u>Ultra-high speed tunability</u> -- electrooptic effect

Photonic microwave filtering via frequency selective modulation

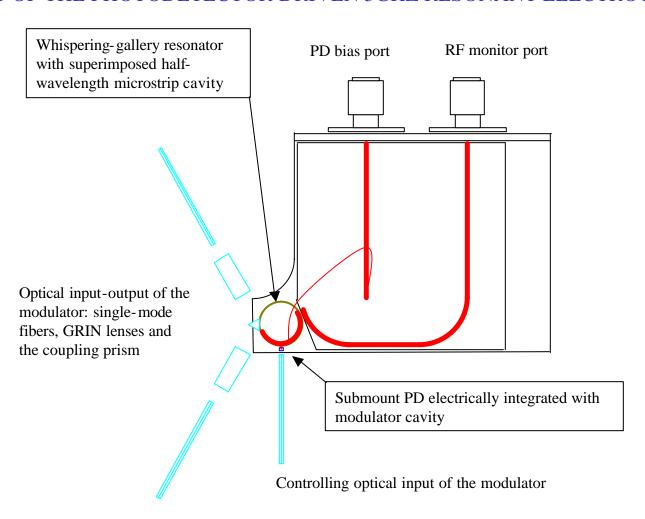


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LAYOUT OF THE PHOTODETECTOR-DRIVEN 5GHZ RESONANT ELECTROOPTIC MODULATOR

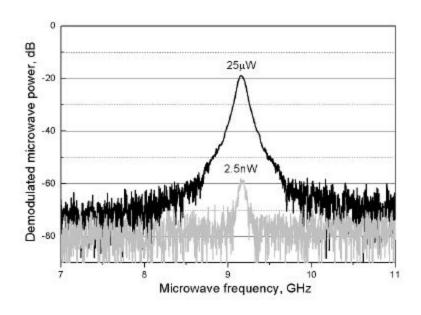


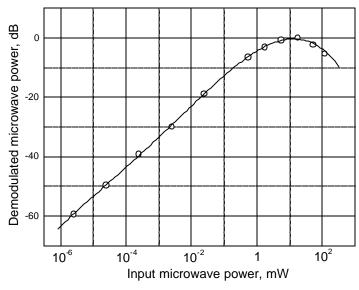
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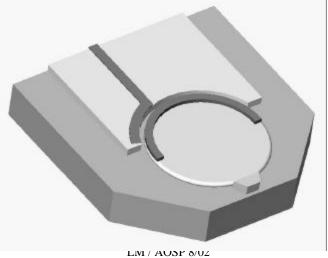


Ultra-High Efficency Modulator/Reciever







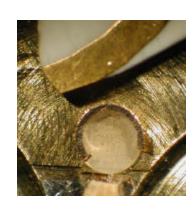


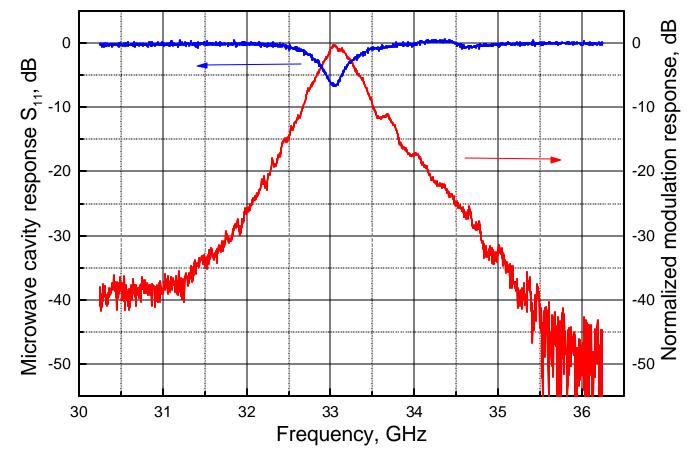


Feasibility of Ka-Band Tunable Filter



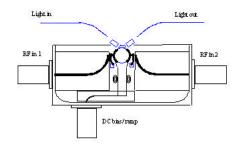
Frequency response of the Ka band LiNbO₃ whispering-gallery mode electrooptical modulator.



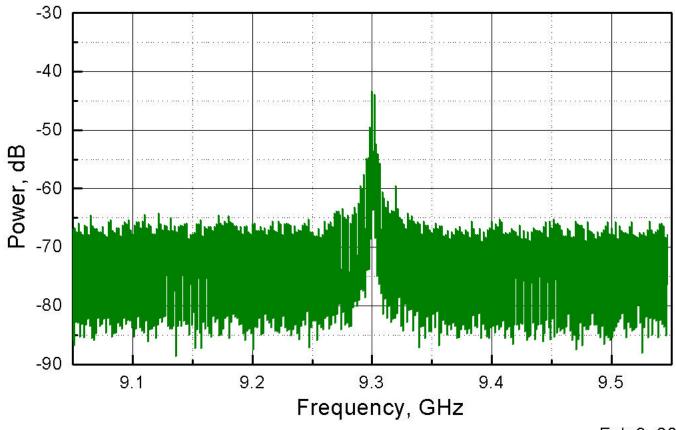


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Power spectrum of the prototype OEO based on the novel WG-mode-type electrooptic modulator



True time delay based on quantum coherence control

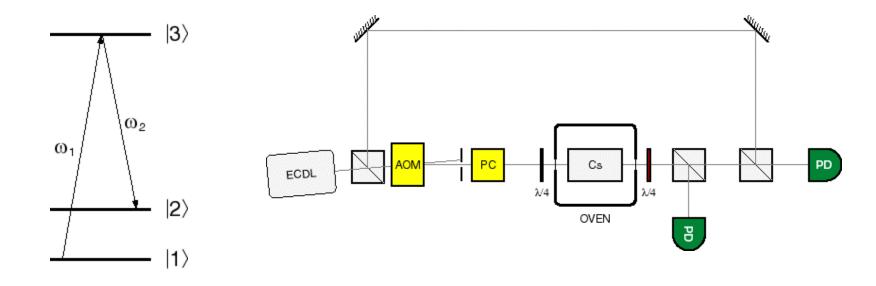


- Novel technique based on "slow light"
- Potential for precision controlled true time delay, widely tunable, limited only by coherence time
 - As short as 1 ns
 - Many micro-seconds of delay achievable
 - Milli-second delays possible
- Based on electromagnetically induced transparency
 - A quantum interference effect
 - Achievable with room temperature, as well as laser cooled samples of atoms



Slow light Experiment





Probe laser at ? 1, coupling laser at ? 2

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Current Status and Future Plans



- Analysis of the noise of the OEO has been completed
- Design of the slow light experiment has been completed

Plans for phase 1

- Demonstrate carrier suppression with 30 dB improvement
- Demonstrate OEO without amplifier
- Demonstrate Slow light